

# yangyan Guo

## List of Publications by Year in descending order

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Version: 2024-02-01

10  
papers

39  
citations

1937685

4  
h-index

1872680

6  
g-index

10  
all docs

10  
docs citations

10  
times ranked

32  
citing authors

#	ARTICLE	IF	CITATIONS
1	Gate-regulated transition temperatures for electron hopping behaviours in silicon junctionless nanowire transistors. Journal of Semiconductors, 2020, 41, 072905.	3.7	5
2	Recent research progress of ferroelectric negative capacitance field effect transistors. Wuli Xuebao/Acta Physica Sinica, 2020, 69, 137701.	0.5	9
3	Low temperature electric field dependent mobility of the current oscillation regime in silicon junctionless nanowire transistor. , 2020, , .		0
4	Observation of hopping transitions for delocalized electrons by temperature-dependent conductance in silicon junctionless nanowire transistors*. Chinese Physics B, 2019, 28, 107303.	1.4	2
5	CubemapSLAM: A Piecewise-Pinhole Monocular Fisheye SLAM System. Lecture Notes in Computer Science, 2019, , 34-49.	1.3	6
6	Temperature-dependent subband mobility characteristics in n-doped silicon junctionless nanowire transistor. Chinese Physics B, 2019, 28, 066804.	1.4	1
7	Single-electron transport through single and coupling dopant atoms in silicon junctionless nanowire transistor. Chinese Physics B, 2019, 28, 127302.	1.4	4
8	One-Dimensional Transport through Two Subbands in Silicon Junctionless Nanowire Transistors. , 2018, , .		0
9	Influence of dopant concentration on electrical quantum transport behaviors in junctionless nanowire transistors. Chinese Physics B, 2018, 27, 088106.	1.4	8
10	Transport spectroscopy through dopant atom array in silicon junctionless nanowire transistors. Chinese Physics B, 2018, 27, 097310.	1.4	4